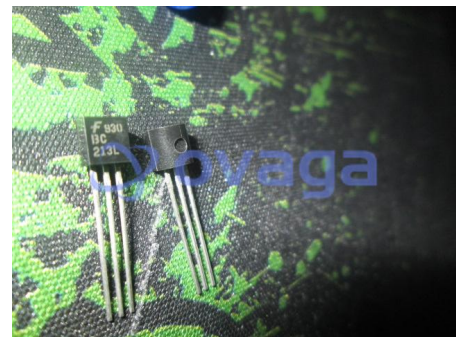


PNP General Purpose Amplifier, Bipolar Transistors PNP -30V -500mA HFE/400

Manufacturers	NXP Semiconductor
Package/Case	TO-92
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for BC213L or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

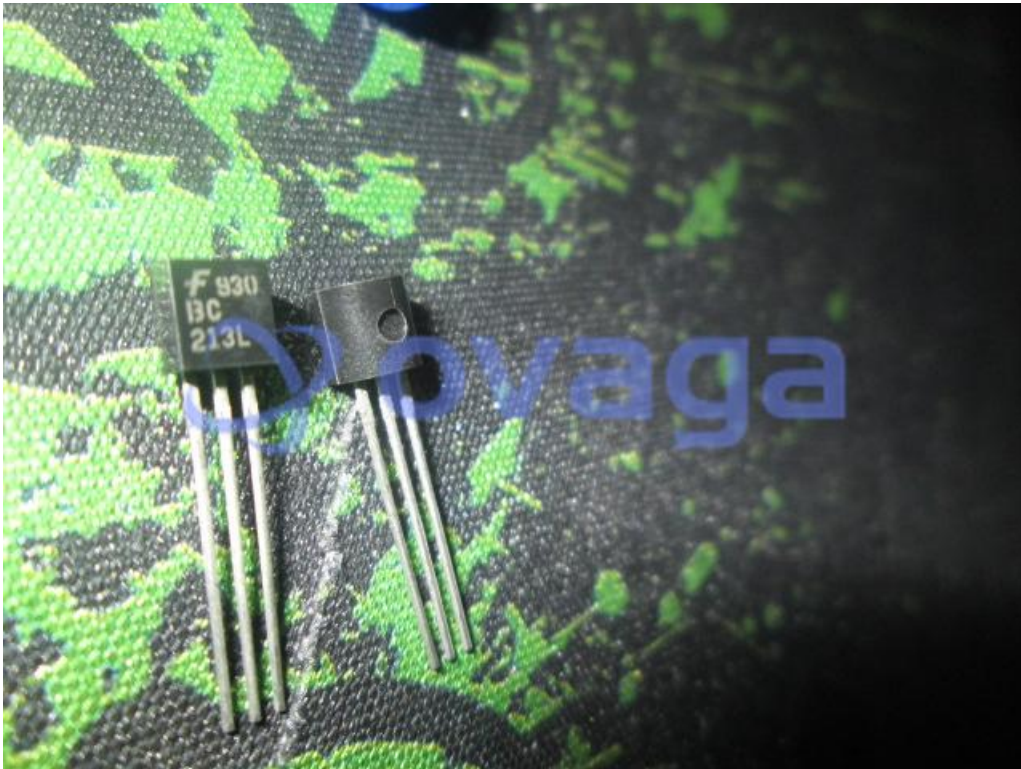
BC213L is a type of bipolar junction transistor (BJT). It is an NPN transistor with a maximum collector current of 500 mA and a maximum collector-emitter voltage of 50 V.

Features

- Low noise and low distortion characteristics
- High current gain (hFE)
- High maximum operating temperature of 150°C
- Small package size (TO-92)

Application

- Audio amplifiers
- Oscillators
- Switches
- Voltage regulators
- Power supplies



Related Products



[BCP52-16](#)

NXP Semiconductor
SOT-223



[BC807](#)

NXP Semiconductor
SOT-23



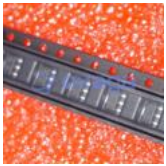
[BC846](#)

NXP Semiconductor
SOT-23



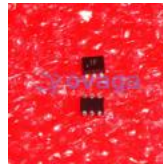
[BCV62C](#)

NXP Semiconductor
SOT-143



[BC869](#)

NXP Semiconductor
SOT-89



[BC847BV](#)

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SOT-666



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[BC807-25](#)

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